SKDT 100



SEMIPONT[®] 2

Controllable Bridge Rectifiers

SKDT 100

Features

- Fully controlled three phase bridge rectifier
- Robust plastic case with screw terminals
- Large, isolated base plate
- Blocking voltage to 1400V
- High surge currents
- Easy chassis mounting
- UL recognized, file no. E 63 532

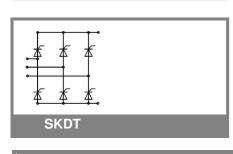
Typical Applications

- For DC drives with a fixed direction of rotation
- Controlled field rectifiers for DC motors
- Controlled battery charger rectifiers

1) Painted metal shield of minimum 250 x 250 x 1 mm: $R_{th(c-a)} = 1.8 \text{ K/W}$

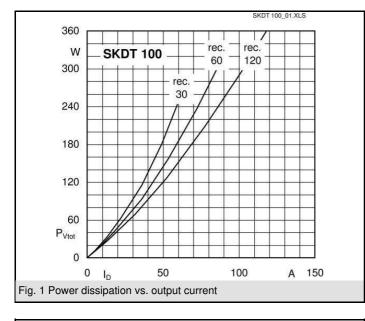
V _{RSM}	V _{RRM} , V _{DRM}	I _D = 100 A (full conduction)
V	V	(T _c = 84 °C)
900	800	SKDT 100/08
1300	1200	SKDT 100/12
1500	1400	SKDT 100/14
1700	1600	SKDT 100/16

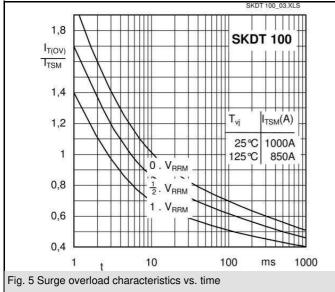
Symbol	Conditions	Values	Units
I _D	T _c = 85 °C	98	А
	T _a = 45 °C; chassis ¹⁾	20	А
	T _a = 45 °C; P13A/125	25	А
	T _a = 45 °C; P1A/120	45	А
I _{TSM} , I _{FSM}	T _{vi} = 25 °C; 10 ms	1000	A
	T _{vi} = 125 °C; 10 ms	850	А
i²t	T _{vj} = 25 °C; 8,3 10 ms	5000	A²s
	T _{vj} = 125 °C; 8,3 10 ms	3600	A²s
V _T	T _{vi} = 25 °C; I _T =200 A	max. 1,95	V
V _{T(TO)}	T _{vi} = 125 °C;	max. 1	V
r _T	T _{vi} = 125 °C	max. 4,5	mΩ
I _{DD} ; I _{RD}	$T_{vj} = 125 \text{ °C}; V_{DD} = V_{DRM}; V_{RD} = V_{RRM}$	max. 15	mA
t _{gd}	T _{vi} = 25 °C; I _G = 1 A; di _G /dt = 1 A/μs	1	μs
t _{gr}	$V_{D} = 0.67 \cdot V_{DRM}$	1	μs
(dv/dt) _{cr}	T _{vi} = 125 °C	max. 500	V/µs
(di/dt) _{cr}	T _{vi} = 125 °C; f = 50 Hz	max. 50	A/µs
t _q	T _{vi} = 125 °C; typ.	80	μs
I _H	$T_{vj} = 25 \text{ °C; typ. / max.}$	100 / 200	mA
I _L	$T_{vj} = 25 \text{ °C}; R_G = 33 \Omega$	250 / 400	mA
V _{GT}	T _{vi} = 25 °C; d.c.	min. 3	V
I _{GT}	T _{vi} = 25 °C; d.c.	min. 150	mA
V _{GD}	T _{vi} = 125 °C; d.c.	max. 0,25	V
I _{GD}	T _{vj} = 125 °C; d.c.	max. 5	mA
R _{th(j-c)}	per thyristor / diode	0,85	K/W
- 0 -/	total	0,141	K/W
R _{th(c-s)}	total	0,05	K/W
T _{vi}		- 40 + 125	.0°
T _{vj} T _{stg}		- 40 + 125	°C
V _{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 (3000)	V
visol M _s	to heatsink	5	Nm
M _s M _t	to terminals	3	Nm
m		165	g
Case	SKDT	G 21	

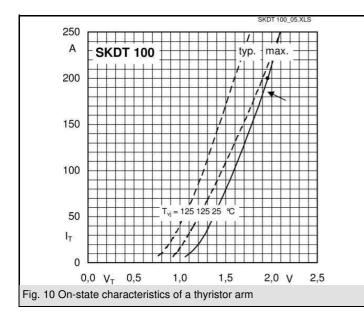


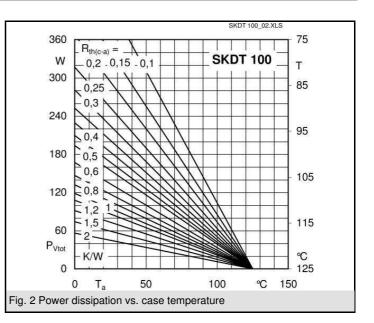
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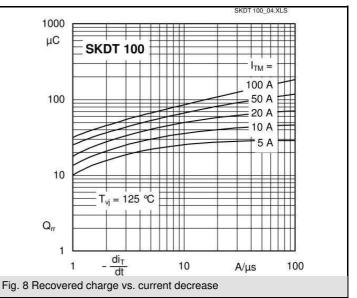
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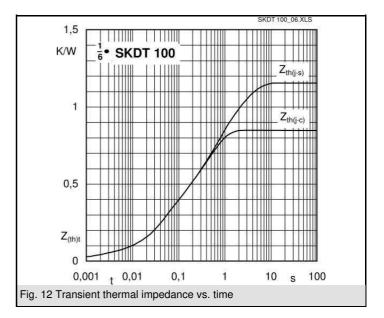






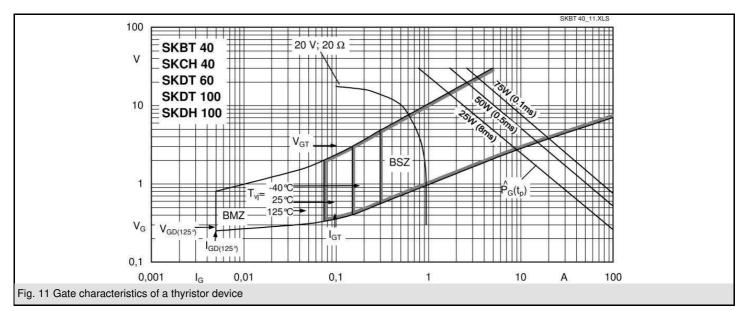


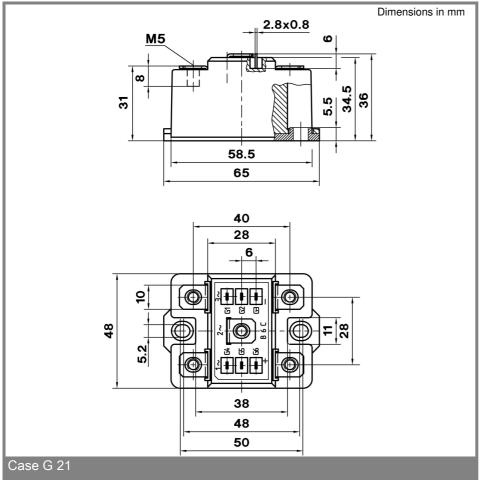




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